# **MOSFET** – Power, **P-Channel, High Side Load** Switch with Level-Shift, **SC-88** 8 V, ±1.3 A

The NTJD1155L integrates a P and N-Channel MOSFET in a single package. This device is particularly suited for portable electronic equipment where low control signals, low battery voltages and high load currents are needed. The P-Channel device is specifically designed as a load switch using ON Semiconductor state-of-the-art trench technology. The N-Channel, with an external resistor (R1), functions as a level-shift to drive the P-Channel. The N-Channel MOSFET has internal ESD protection and can be driven by logic signals as low as 1.5 V. The NTJD1155L operates on supply lines from 1.8 to 8.0 V and can drive loads up to 1.3 A with 8.0 V applied to both VIN and VON/OFF.

### Features

- Extremely Low R<sub>DS(on)</sub> P-Channel Load Switch MOSFET
- Level Shift MOSFET is ESD Protected
- Low Profile, Small Footprint Package
- V<sub>IN</sub> Range 1.8 to 8.0 V
- ON/OFF Range 1.5 to 8.0 V
- These Devices are Pb-Free and are RoHS Compliant

### MAXIMUM RATINGS (T<sub>J</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit		
Input Voltage (V <sub>DSS</sub> , P-Ch)			V <sub>IN</sub>	8.0	V
ON/OFF Voltage (V <sub>GS</sub> , N-	Ch)		V <sub>ON/OFF</sub>	8.0	V
Continuous Load Current	Steady $T_A = 25^{\circ}C$		١L	±1.3	А
(Note 1)	State	$T_A = 85^{\circ}C$		±0.9	
Power Dissipation	Steady State	$T_A = 25^{\circ}C$	PD	0.40	W
(Note 1)		$T_A = 85^{\circ}C$		0.20	
Pulsed Load Current	t <sub>p</sub> =	10 μs	I <sub>LM</sub>	±3.9	А
Operating Junction and Storage Temperature			T <sub>J</sub> , T <sub>STG</sub>	–55 to 150	°C
Source Current (Body Diode)			۱ <sub>S</sub>	-0.4	А
Lead Temperature for Sold (1/8" from case for 10 s)	ΤL	260	°C		

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Junction-to-Ambient - Steady State (Note 1)	$R_{\theta JA}$	320	°C/W
Junction-to-Foot - Steady State (Note 1)	$R_{\theta JF}$	220	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

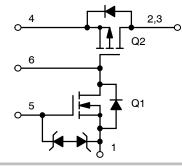


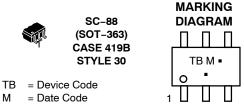
# **ON Semiconductor®**

### www.onsemi.com

V <sub>(BR)DSS</sub>	R <sub>DS(on)</sub> TYP	I <sub>D</sub> MAX
	130 mΩ @ –4.5 V	
8.0 V	170 mΩ @ –2.5 V	±1.3 A
	260 mΩ @ –1.8 V	

## SIMPLIFIED SCHEMATIC







Μ

(Note: Microdot may be in either location)

**PIN ASSIGNMENT** 

# D1/G2 G1 S2 2 3 D2 D2 **S**1

## **ORDERING INFORMATION**

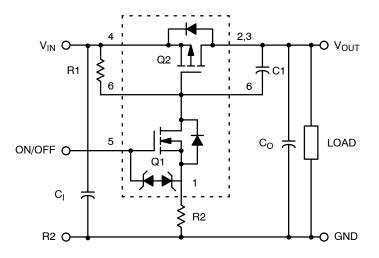
Device	Package	Shipping <sup>†</sup>
NTJD1155LT1G, NTJD1155LT2G	SC-88 (Pb-Free)	3000/Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

1. Surface-mounted on FR4 board using 1 inch sq pad size (Cu area = 1.127 in sq [1 oz] including traces).

## **ELECTRICAL CHARACTERISTICS** (T<sub>J</sub> = $25^{\circ}C$ unless otherwise noted)

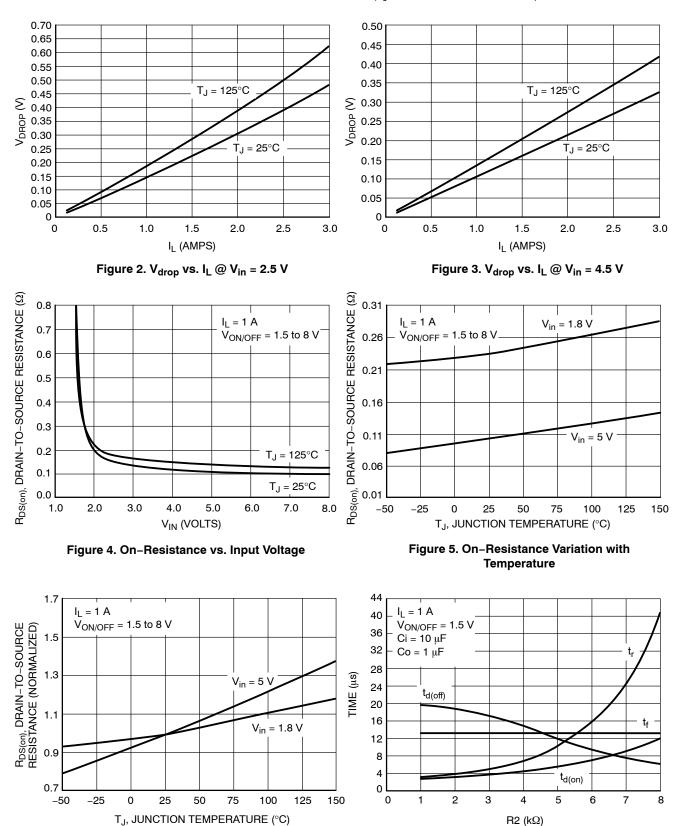
Characteristic	Symbol	Test Cond	Test Condition		Тур	Max	Unit
OFF CHARACTERISTICS		-					
Q2 Drain-to-Source Breakdown Voltage	V <sub>IN</sub>	$V_{GS2}$ = 0 V, $I_{D2}$	= 250 μA	-8.0			V
Forward Leakage Current	I <sub>FL</sub>	V <sub>GS1</sub> = 0 V,	$T_J = 25^{\circ}C$			1.0	μΑ
		$V_{DS2} = -8.0$ V	T <sub>J</sub> = 125°C			10	
Q1 Gate-to-Source Leakage Current	I <sub>GSS</sub>	V <sub>DS1</sub> = 0 V, V <sub>GS</sub>	<sub>1</sub> = ±8.0 V			±100	nA
Q1 Diode Forward On-Voltage	V <sub>SD</sub>	I <sub>S</sub> = -0.4 A, V <sub>G</sub>	<sub>S1</sub> = 0 V		-0.8	-1.1	V
ON CHARACTERISTICS							
ON/OFF Voltage	V <sub>ON/OFF</sub>			1.5		8.0	V
Q1 Gate Threshold Voltage	V <sub>GS1(th)</sub>	$V_{GS1} = V_{DS1}, I_D = 250 \ \mu A$		0.4		1.0	V
Input Voltage	V <sub>IN</sub>	$V_{GS1} = V_{DS1}, I_D = 250 \ \mu A$		1.8		8.0	V
Q2 Drain-to-Source On Resistance	R <sub>DS(on)</sub>	V <sub>ON/OFF</sub> = 1.5 V	V <sub>IN</sub> = 4.5 V I <sub>L</sub> = 1.2 A		130	175	mΩ
			V <sub>IN</sub> = 2.5 V I <sub>L</sub> = 1.0 A		170	220	
			V <sub>IN</sub> = 1.8 V I <sub>L</sub> = 0.7 A		260	320	
Load Current	۱ <sub>L</sub>	$V_{DROP} \le 0.2 \text{ V}, \text{ V}$ $V_{ON/OFF} = 7$		1.0			A
		$V_{DROP} \le 0.3 \text{ V}, \text{ V}$ $V_{ON/OFF} = 7$	/ <sub>IN</sub> = 2.5 V, 1.5 V	1.0			





Components	Description	Values
R1	Pullup Resistor	Typical 10 k $\Omega$ to 1.0 M $\Omega^*$
R2	Optional Slew-Rate Control	Typical 0 to 100 kΩ*
C <sub>O</sub> , C <sub>I</sub>	Output Capacitance	Usually < 1.0 μF
C1	Optional In-Rush Current Control	Typical ≤ 1000 pF

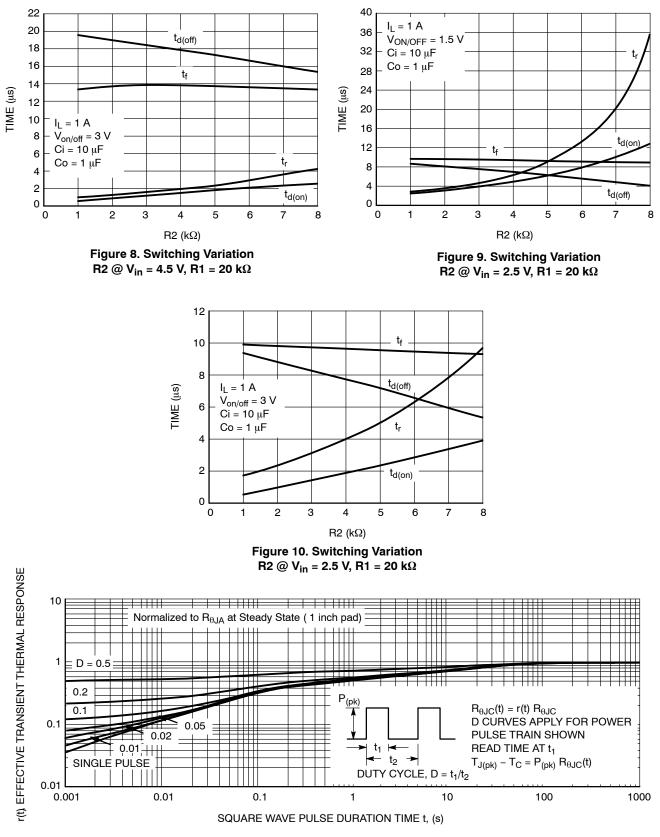
\*Minimum R1 value should be at least 10 x R2 to ensure Q1 turn-on.



# TYPICAL PERFORMANCE CURVES (T<sub>J</sub> = $25^{\circ}$ C unless otherwise noted)



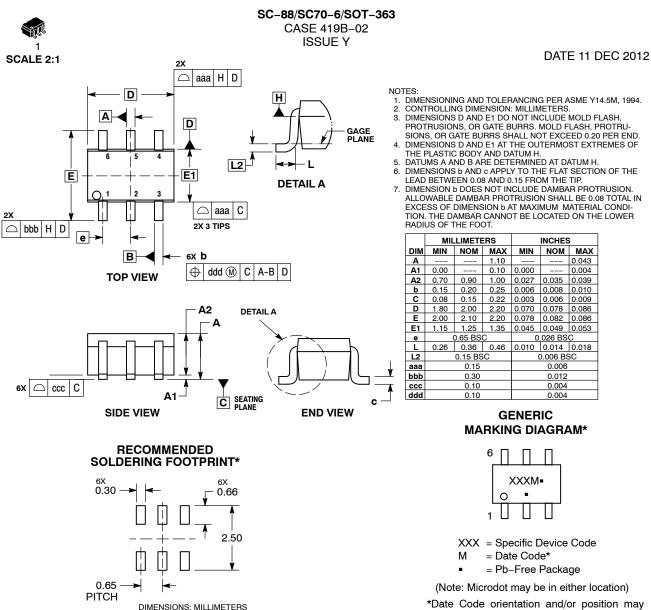




# **TYPICAL PERFORMANCE CURVES** (T<sub>J</sub> = $25^{\circ}$ C unless otherwise noted)







- \*Date Code orientation and/or position may vary depending upon manufacturing location.
  - \*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " •", may or may not be present.

## **STYLES ON PAGE 2**

DOCUMENT NUMBER:	98ASB42985B	Electronic versions are uncontrolled except when accessed directly from the Document Repository Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.				
DESCRIPTION: SC-88/SC70-6/SOT-363 PA						
ON Semiconductor and I are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.						

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and

Mounting Techniques Reference Manual, SOLDERRM/D.

#### SC-88/SC70-6/SOT-363 CASE 419B-02 ISSUE Y

## DATE 11 DEC 2012

STYLE 1: PIN 1. EMITTER 2 2. BASE 2 3. COLLECTOR 1 4. EMITTER 1 5. BASE 1 6. COLLECTOR 2	STYLE 2: CANCELLED	STYLE 3: CANCELLED	STYLE 4: PIN 1. CATHODE 2. CATHODE 3. COLLECTOR 4. EMITTER 5. BASE 6. ANODE	STYLE 5: PIN 1. ANODE 2. ANODE 3. COLLECTOR 4. EMITTER 5. BASE 6. CATHODE	STYLE 6: PIN 1. ANODE 2 2. N/C 3. CATHODE 1 4. ANODE 1 5. N/C 6. CATHODE 2
STYLE 7: PIN 1. SOURCE 2 2. DRAIN 2 3. GATE 1 4. SOURCE 1 5. DRAIN 1 6. GATE 2	STYLE 8: CANCELLED	STYLE 9: PIN 1. EMITTER 2 2. EMITTER 1 3. COLLECTOR 1 4. BASE 1 5. BASE 2 6. COLLECTOR 2	STYLE 10: PIN 1. SOURCE 2 2. SOURCE 1 3. GATE 1 4. DRAIN 1 5. DRAIN 2 6. GATE 2	STYLE 11: PIN 1. CATHODE 2 2. CATHODE 2 3. ANODE 1 4. CATHODE 1 5. CATHODE 1 6. ANODE 2	STYLE 12: PIN 1. ANODE 2 2. ANODE 2 3. CATHODE 1 4. ANODE 1 5. ANODE 1 6. CATHODE 2
STYLE 13:	STYLE 14:	STYLE 15:	STYLE 16:	STYLE 17:	STYLE 18:
PIN 1. ANODE	PIN 1. VREF	PIN 1. ANODE 1	PIN 1. BASE 1	PIN 1. BASE 1	PIN 1. VIN1
2. N/C	2. GND	2. ANODE 2	2. EMITTER 2	2. EMITTER 1	2. VCC
3. COLLECTOR	3. GND	3. ANODE 3	3. COLLECTOR 2	3. COLLECTOR 2	3. VOUT2
4. EMITTER	4. IOUT	4. CATHODE 3	4. BASE 2	4. BASE 2	4. VIN2
5. BASE	5. VEN	5. CATHODE 2	5. EMITTER 1	5. EMITTER 2	5. GND
6. CATHODE	6. VCC	6. CATHODE 1	6. COLLECTOR 1	6. COLLECTOR 1	6. VOUT1
STYLE 19:	STYLE 20:	STYLE 21:	STYLE 22:	STYLE 23:	STYLE 24:
PIN 1. I OUT	PIN 1. COLLECTOR	PIN 1. ANODE 1	PIN 1. D1 (i)	PIN 1. Vn	PIN 1. CATHODE
2. GND	2. COLLECTOR	2. N/C	2. GND	2. CH1	2. ANODE
3. GND	3. BASE	3. ANODE 2	3. D2 (i)	3. Vp	3. CATHODE
4. V CC	4. EMITTER	4. CATHODE 2	4. D2 (c)	4. N/C	4. CATHODE
5. V EN	5. COLLECTOR	5. N/C	5. VBUS	5. CH2	5. CATHODE
6. V REF	6. COLLECTOR	6. CATHODE 1	6. D1 (c)	6. N/C	6. CATHODE
STYLE 25:	STYLE 26:	STYLE 27:	STYLE 28:	STYLE 29:	STYLE 30:
PIN 1. BASE 1	PIN 1. SOURCE 1	PIN 1. BASE 2	PIN 1. DRAIN	PIN 1. ANODE	PIN 1. SOURCE 1
2. CATHODE	2. GATE 1	2. BASE 1	2. DRAIN	2. ANODE	2. DRAIN 2
3. COLLECTOR 2	3. DRAIN 2	3. COLLECTOR 1	3. GATE	3. COLLECTOR	3. DRAIN 2
4. BASE 2	4. SOURCE 2	4. EMITTER 1	4. SOURCE	4. EMITTER	4. SOURCE 2
5. EMITTER	5. GATE 2	5. EMITTER 2	5. DRAIN	5. BASE/ANODE	5. GATE 1
6. COLLECTOR 1	6. DRAIN 1	6. COLLECTOR 2	6. DRAIN	6. CATHODE	6. DRAIN 1

DOCUMENT NUMBER:	98ASB42985B Electronic versions are uncontrolled except when accessed directly from the Document Repositor Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.				
DESCRIPTION:	SC-88/SC70-6/SOT-363		PAGE 2 OF 2		
ON Semiconductor and Mare trademarks of Semiconductor Components Industries. LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries.					

ON Semiconductor and united states and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor date sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use a a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor houteds for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries

#### PUBLICATION ORDERING INFORMATION

#### LITERATURE FULFILLMENT:

#### TECHNICAL SUPPORT

ON Semiconductor Website: www.onsemi.com

Email Requests to: orderlit@onsemi.com

North American Technical Support: Voice Mail: 1 800–282–9855 Toll Free USA/Canada Phone: 011 421 33 790 2910 Europe, Middle East and Africa Technical Support: Phone: 00421 33 790 2910 For additional information, please contact your local Sales Representative

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for MOSFET category:

Click to view products by ON Semiconductor manufacturer:

Other Similar products are found below :

614233C 648584F MCH3443-TL-E MCH6422-TL-E FW231A-TL-E APT5010JVR NTNS3A92PZT5G IRF100S201 JANTX2N5237 2SK2464-TL-E 2SK3818-DL-E FCA20N60\_F109 FDZ595PZ STD6600NT4G FSS804-TL-E 2SJ277-DL-E 2SK1691-DL-E 2SK2545(Q,T) 405094E 423220D MCH6646-TL-E TPCC8103,L1Q(CM 367-8430-0972-503 VN1206L 424134F 026935X 051075F SBVS138LT1G 614234A 715780A NTNS3166NZT5G 751625C 873612G IRF7380TRHR IPS70R2K0CEAKMA1 RJK60S3DPP-E0#T2 RJK60S5DPK-M0#T0 APT5010JVFR APT12031JFLL APT12040JVR DMN3404LQ-7 NTE6400 JANTX2N6796U JANTX2N6784U JANTXV2N5416U4 SQM110N05-06L-GE3 SIHF35N60E-GE3 2SK2614(TE16L1,Q) 2N7002KW-FAI APT1201R6BVFRG